NSN 5962-01-444-9547

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View Online at https://aerobasegroup.com/nsn/5962-01-444-9547

Body Length:
0.458 inches
Body Width:
0.458 inches
Body Height:
0.180 inches
Maximum Power Dissipation Rating:
1.5 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
F-15i
Features Provided:
Electrostatic sensitive and ultraviolet erasable and programmable and monolithic
Inclosure Material:
Silicon
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
24 input
Criticality Code Justification:
Cbbl
Case Outline Source And Designator:
D-15 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
Firmware, microcircuit, digital-programmable logic
Voltage Rating And Type Per Characteristic:
-2.0 volts total supply and 7.0 volts total supply
Memory Device Type:
Pal
Special Features:
Altered item, make from 5962-9061102yx, fielded software (pof file) version identification 8521165.101
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
00 artists districtly

28 printed circuit

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N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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